

# 0.5-12 GHz General Purpose Gallium Arsenide FET

## Technical Data

#### ATF-10736

#### **Features**

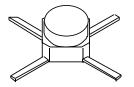
- **High Associated Gain:** 13.0 dB Typical at 4 GHz
- **Low Bias:**  $V_{DS} = 2 V, I_{DS} = 25 \text{ mA}$
- **High Output Power:** 20.0 dBm typical P<sub>1dB</sub> at 4 GHz
- Low Noise Figure: 1.2 dB Typical at 4 GHz
- Cost Effective Ceramic Microstrip Package
- Tape-and-Reel Packaging Option Available [1]

## **Description**

The ATF-10736 is a high performance gallium arsenide Schottky-barrier-gate field effect transistor housed in a cost effective microstrip package. Its noise figure makes this device appropriate for use in the gain stages of low noise amplifiers operating in the 0.5-12 GHz frequency range.

This GaAs FET device has a nominal 0.3 micron gate length using airbridge interconcnects between drain fingers. Total gate periphery is 500 microns. Proven gold based metallization systems and nitride passivation assure a rugged, reliable device.

### 36 micro-X Package



## Electrical Specifications, $T_A = 25$ °C

| Symbol             | <b>Parameters and Test Conditions</b>   |                        | Units | Min. | Тур. | Max. |
|--------------------|---|------------------------|-------|------|------|------|
| $NF_{O}$           | Optimum Noise Figure: $V_{DS} = 2 \text{ V}$ , $I_{DS} = 25 \text{ mA}$                             | f = 2.0  GHz           | dB    |      | 0.9  |      |
|                    |   | f = 4.0  GHz           | dB    |      | 1.2  | 1.4  |
|                    |   | $f = 6.0 \mathrm{GHz}$ | dB    |      | 1.4  |      |
| $G_{A}$            | Gain @ NF <sub>O</sub> ; $V_{DS} = 2 \text{ V}$ , $I_{DS} = 25 \text{ mA}$                          | $f = 2.0 \mathrm{GHz}$ | dB    |      | 16.5 |      |
|                    |   | f = 4.0 GHz            | dB    | 12.0 | 13.0 |      |
|                    |   | $f = 6.0 \mathrm{GHz}$ | dB    |      | 10.5 |      |
| $P_{1 dB}$         | Power Output @ 1 dB Gain Compression  | f = 4.0  GHz           | dBm   |      | 20.0 |      |
|                    | $V_{\rm DS} = 4  \mathrm{V}, I_{\rm DS} = 70  \mathrm{mA}$  |                        |       |      |      |      |
| $G_{1dB}$          | $1~\mathrm{dB}$ Compressed Gain: $\mathrm{V_{DS}} = 4~\mathrm{V}, \mathrm{I_{DS}} = 70~\mathrm{mA}$ | f = 4.0  GHz           | dB    |      | 12.0 |      |
| g <sub>m</sub>     | Transconductance: $V_{DS} = 2 V$ , $V_{GS} = 0 V$   |                        | mmho  | 70   | 140  |      |
| $I_{\mathrm{DSS}}$ | Saturated Drain Current: $V_{DS} = 2 V$ , $V_{GS} = 0 V$  |                        | mA    | 70   | 130  | 180  |
| $V_{\rm P}$        | Pinchoff Voltage: $V_{DS} = 2 V$ , $I_{DS} = 1 mA$  |                        | V     | -4.0 | -1.3 | -0.5 |

#### Note:

1. Refer to PACKAGING section, "Tape-and-Reel Packaging for Surface Mount Semiconductors."

**ATF-10736 Absolute Maximum Ratings** 

|                    |                                    |                      | Absolute               |
|--------------------|------------------------------------|----------------------|------------------------|
| Symbol             | Parameter                          | Units                | Maximum <sup>[1]</sup> |
| $ m V_{DS}$        | Drain-Source Voltage               | V                    | +5                     |
| $ m V_{GS}$        | Gate-Source Voltage                | V                    | -4                     |
| $V_{ m GD}$        | Gate-Drain Voltage                 | V                    | -7                     |
| $I_{\mathrm{DS}}$  | Drain Current                      | mA                   | $I_{\mathrm{DSS}}$     |
| $P_{T}$            | Total Power Dissipation [2,3]      | mW                   | 430                    |
| $T_{\mathrm{CH}}$  | Channel Temperature                | $^{\circ}\mathrm{C}$ | 175                    |
| $T_{\mathrm{STG}}$ | Storage Temperature <sup>[4]</sup> | $^{\circ}\mathrm{C}$ | -65 to +175            |

| Thermal Resistance:         | $\theta_{\rm jc} = 350 {\rm ^{\circ}C/W}; T_{\rm CH} = 150 {\rm ^{\circ}C}$ |
|-----------------------------|---|
| Liquid Crystal Measurement: | $1 \mu m \operatorname{Spot} \operatorname{Size}^{[5]}$                     |

**Part Number Ordering Information** 

| Part Number   | Devices Per Reel | Reel Size |  |  |
|---------------|------------------|-----------|--|--|
| ATF-10736-TR1 | 1000             | 7"        |  |  |
| ATF-10736-STR | 10               | STRIP     |  |  |

For more information, see "Tape and Reel Packaging for Semiconductor Devices."

## ATF-10736 Noise Parameters: $V_{DS} = 2 V$ , $I_{DS} = 25 \text{ mA}$

| Freq. | NFo | $\Gamma_{c}$ | D /50 |            |  |
|-------|-----|--------------|-------|------------|--|
| GHz   | dB  | Mag          | Ang   | $R_{N}/50$ |  |
| 1.0   | 0.8 | 0.88         | 41    | 0.52       |  |
| 2.0   | 0.9 | 0.75         | 85    | 0.27       |  |
| 4.0   | 1.2 | 0.48         | 159   | 0.08       |  |
| 6.0   | 1.4 | 0.46         | -122  | 0.08       |  |
| 8.0   | 1.7 | 0.53         | -71   | 0.43       |  |

## ATF-10736 Typical Performance, $T_A = 25^{\circ}C$

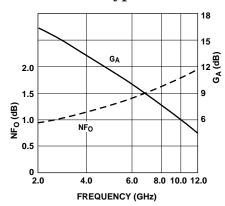


Figure 1. Optimum Noise Figure and Associated Gain vs. Frequency.  $V_{DS}=2V,\,I_{DS}=25$  mA,  $T_A=25^{\circ}C.$ 

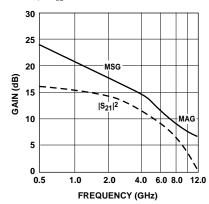


Figure 2. Insertion Power Gain, Maximum Available Gain and Maximum Stable Gain vs. Frequency.  $V_{DS}=2\ V,\ I_{DS}=25\ mA.$ 

#### Notes:

- 1. Permanent damage may occur if any of these limits are exceeded.
- 2.  $T_{CASE\ TEMPERATURE} = 25$ °C.
- 3. Derate at 2.9 mW/°C for  $T_{CASE} > 25$ °C.
- 4. Storage above +150°C may tarnish the leads of this package difficult to solder into a circuit. After a device has been soldered into a circuit, it may be safely stored up to 175°C.
- 5. The small spot size of this technique results in a higher, though more accurate determination of  $\theta_{jc}$  than do alternate methods. See MEASUREMENTS section for more information.

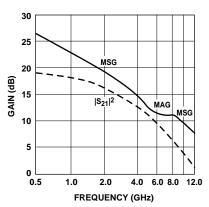


Figure 3. Insertion Power Gain, Maximum Available Gain and Maximum Stable Gain vs. Frequency.  $V_{DS}=4\ V,\ I_{DS}=70\ mA.$ 

 $\textbf{Typical Scattering Parameters,} \ Common \ Source, \ Z_O = 50 \ \Omega, T_A = 25 ^{\circ}\!C, V_{DS} = 2 \ V, I_{DS} = 25 \ mA$ 

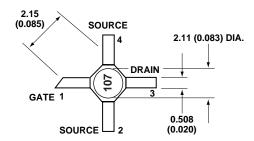
| Freq. | S    | $\mathbf{S}_{11}$ |      | $\mathbf{S_{21}}$ |      | $\mathbf{S_{12}}$ |      | S           | 22   |             |
|-------|------|-------------------|------|-------------------|------|-------------------|------|-------------|------|-------------|
| GHz   | Mag. | Ang.              | dB   | Mag.              | Ang. | dB                | Mag. | Ang.        | Mag. | Ang.        |
| 0.5   | .96  | -20               | 15.4 | 5.90              | 162  | -32.4             | .024 | 77          | .50  | -10         |
| 1.0   | .92  | <b>-4</b> 0       | 15.2 | 5.77              | 144  | -26.7             | .046 | 66          | .48  | -21         |
| 2.0   | .77  | -76               | 13.8 | 4.92              | 109  | -21.3             | .086 | 52          | .39  | -34         |
| 3.0   | .59  | -107              | 12.5 | 4.20              | 83   | -20.0             | .111 | 40          | .33  | <b>-</b> 45 |
| 4.0   | .49  | -136              | 11.2 | 3.64              | 57   | -17.3             | .137 | 24          | .26  | <b>-</b> 61 |
| 5.0   | .43  | -179              | 10.0 | 3.15              | 32   | -15.5             | .167 | 9           | .14  | <b>-</b> 65 |
| 6.0   | .49  | 138               | 8.6  | 2.74              | 8    | -14.9             | .179 | <b>-</b> 5  | .05  | 22          |
| 7.0   | .57  | 106               | 7.3  | 2.32              | -13  | -14.8             | .183 | -18         | .19  | 60          |
| 8.0   | .68  | 81                | 5.6  | 1.92              | -32  | -14.7             | .185 | -33         | .33  | 57          |
| 9.0   | .73  | 62                | 4.2  | 1.62              | -50  | -14.8             | .183 | <b>-4</b> 0 | .42  | 46          |
| 10.0  | .77  | 47                | 3.0  | 1.41              | -66  | -14.8             | .182 | <b>-</b> 52 | .46  | 38          |
| 11.0  | .82  | 36                | 1.0  | 1.12              | -81  | -14.6             | .186 | -67         | .50  | 27          |
| 12.0  | .85  | 22                | -0.2 | 0.98              | -97  | -14.5             | .189 | -75         | .51  | 15          |

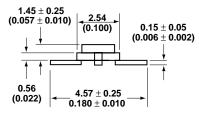
 $\textbf{Typical Scattering Parameters,} \ Common \ Emitter, \ Z_O = 50 \ \Omega, T_A = 25 ^{\circ}\text{C}, V_{DS} = 4 \ V, I_{DS} = 70 \text{mA}$ 

| Freq. | S    | $\mathbf{S}_{11}$ |      | $\mathbf{S}_{21}$ |             | $\mathbf{S}_{12}$ |      | S           | 22   |             |
|-------|------|-------------------|------|-------------------|-------------|-------------------|------|-------------|------|-------------|
| GHz   | Mag. | Ang.              | dB   | Mag.              | Ang.        | dB                | Mag. | Ang.        | Mag. | Ang.        |
| 0.5   | .90  | -32               | 19.0 | 8.95              | 147         | -34.9             | .018 | 77          | .40  | -7          |
| 1.0   | .79  | -53               | 18.0 | 7.96              | 128         | -28.6             | .037 | 70          | .38  | -17         |
| 2.0   | .57  | -96               | 15.5 | 5.99              | 90          | -22.5             | .075 | 56          | .34  | -38         |
| 3.0   | .43  | -129              | 13.3 | 4.60              | 64          | -19.5             | .106 | 43          | .31  | -50         |
| 4.0   | .36  | -163              | 11.6 | 3.78              | 39          | -17.3             | .136 | 31          | .28  | -51         |
| 5.0   | .35  | 156               | 10.1 | 3.21              | 16          | -15.6             | .166 | 14          | .22  | <b>-</b> 45 |
| 6.0   | .47  | 110               | 8.8  | 2.76              | -11         | -14.5             | .189 | <b>-</b> 5  | .15  | -4          |
| 7.0   | .65  | 78                | 7.0  | 2.23              | -36         | -14.2             | .196 | <b>-</b> 23 | .28  | 35          |
| 8.0   | .77  | 58                | 5.1  | 1.80              | -56         | -14.1             | .198 | -38         | .42  | 37          |
| 9.0   | .83  | 44                | 3.5  | 1.50              | <b>-7</b> 2 | -14.2             | .195 | -48         | .51  | 33          |
| 10.0  | .86  | 30                | 2.4  | 1.32              | -88         | -14.5             | .188 | <b>-</b> 64 | .55  | 26          |
| 11.0  | .87  | 16                | 1.1  | 1.13              | -106        | -14.8             | .182 | -77         | .60  | 18          |
| 12.0  | .91  | 1                 | 0.1  | 0.99              | -123        | -15.3             | .171 | <b>-</b> 91 | .65  | 7           |

A model for this device is available in the DEVICE MODELS section.

## 36 micro-X Package Dimensions





- 1. Dimensions are in millimeters (inches)
  2. Tolerances: in .xxx = ± 0.005
  mm .xx = ± 0.13